Sheet 1 of 1 | INFORMATION DISCLOSURE STATEMENT

FORM PTO 1449 (*modified*)

U.S. DEPARTMENT OF COMMERCE
PATENT AND TRADEMARK OFFICE

LIST OF REFERENCES CITED BY APPLICANT(S)
(*Use several sheets if necessary*)

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ATTY DOCKET NO.	SERIAL NO.
2006_1009A	10/584,091

APPLICANT: Kiminori MIZUUCHI et al.

FILING DATE	GROUP
June 22, 2006	2828

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
	AA	4,882,607	11/1989	Shinada			
	AB	6,649,938	11/2003	Bogatov et al.			
	AC	4,932,034	6/1990	Usami et al.			
	AD						

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES	TRANSLATION NO
	AE	0 332 453	9/1989	EP			X	
	AF	1 063 743	12/2000	EP			X	
	AG	58-50790	3/1983	JP			Abstract	
	AH							
	AI							

OTHER DOCUMENT(S) (*Including Author, Title, Date, Pertinent Pages, Etc.*)

	AJ	European Search Report issued September 5, 2007 in European Patent Application EP 04 80 7480.
	AK	Körbl, M. et al., "Electronic wavelength tuning of multisegment InGaAsP/InP lasers with laterally coupled absorptive DFB gratings", Solid-State Electronics, vol. 47, no. 4 April 2003, pp 741-745.
	AL	Kuhn, J. et al., "Dynamic Properties of GaInP Multielectrode Ridge-Waveguide Lasers", Semiconductor Science and Technology, vol. 12, no. 4, April 1997, pp. 439-442.
	AM	Sheng-Hui Yang et al. "Generation of High-Power Picosecond Pulses from a Gain-Switched Two-Section Quantum-Well Laser with a Laterally Tapered Energy-Storing Section", IEEE Photonics Technology Letters, vol. 8, no. 3, March 1996, pp. 337-339.
	AN	Seltzer, C.P. et al, "The Gain-Lever Effect in InGaAsP/InP Multiple Quantum Well Lasers", Journal of Lightwave Technology" vol.13, no. 2, February 1995, pp. 283-289.

EXAMINER	/Dung Nguyen/ (03/19/2008)	DATE CONSIDERED	

*EXAMINER: *Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.*

ALL REFERENCES CONSIDERED EXCEPT WHERE LINED THROUGH. /D.N./